

LM185-1.2-N/LM285-1.2-N/LM385-1.2-N Micropower Voltage Reference Diode

Check for Samples: [LM185-1.2-N](#), [LM285-1.2-N](#), [LM385-1.2-N](#)

FEATURES

- $\pm 1\%$ and 2% Initial Tolerance
- Operating Current of $10\mu\text{A}$ to 20mA
- 1Ω Dynamic Impedance
- Low Temperature Coefficient
- Low Voltage Reference— 1.235V
- 2.5V Device and Adjustable Device Also Available
- LM185-2.5 Series and LM185 Series, respectively

DESCRIPTION

The LM185-1.2-N/LM285-1.2-N/LM385-1.2-N are micropower 2-terminal band-gap voltage regulator diodes. Operating over a $10\mu\text{A}$ to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185-1.2-N band-gap reference uses only transistors and resistors, low noise and good long term stability result.

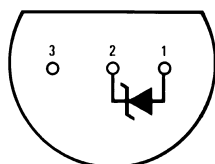
Careful design of the LM185-1.2-N has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-1.2-N makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life.

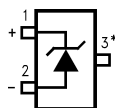
Further, the wide operating current allows it to replace older references with a tighter tolerance part.

The LM185-1.2-N is rated for operation over a -55°C to 125°C temperature range while the LM285-1.2-N is rated -40°C to 85°C and the LM385-1.2-N 0°C to 70°C . The LM185-1.2-N/LM285-1.2-N are available in a hermetic TO package and the LM285-1.2-N/LM385-1.2-N are also available in a low-cost TO-92 molded package, as well as SOIC and SOT-23.

CONNECTION DIAGRAM



**Figure 1. T0-92 Package (LP)
(Bottom View)**



* Pin 3 is attached to the Die Attach Pad (DAP) and should be connected to Pin 2 or left floating.

Figure 2. SOT-23

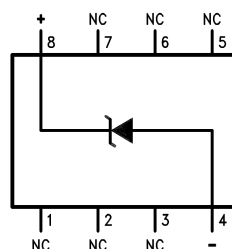
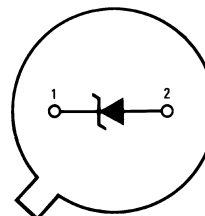


Figure 3. SOIC Package



**Figure 4. TO Package (NDV)
(Bottom View)**



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾⁽³⁾

Reverse Current	30mA
Forward Current	10mA
Operating Temperature Range ⁽⁴⁾	
LM185-1.2-N	–55°C to +125°C
LM285-1.2-N	–40°C to +85°C
LM385-1.2-N	0°C to 70°C
ESD Susceptibility ⁽⁵⁾	2kV
Storage Temperature	–55°C to +150°C
Soldering Information	
TO-92 package: 10 sec.	260°C
TO package: 10 sec.	300°C
SOIC and SOT-23 Pkg.	
Vapor phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.	

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional. For specifications and test conditions, see the Electrical Characteristics. The specifications apply only for the test conditions listed.
- (2) Refer to RETS185H-1.2 for military specifications.
- (3) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (4) For elevated temperature operation, see [Table 1](#).
- (5) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin.

Table 1. $T_{J(max)}$ for Elevated Temperature Operation

DEVICE	$T_{J(max)}$ (°C)
LM185-1.2-N	150
LM285-1.2-N	125
LM385-1.2-N	100

ELECTRICAL CHARACTERISTICS⁽¹⁾

Parameter	Conditions	Typ	LM185-1.2-N LM185BX-1.2-N LM185BY-1.2-N LM285-1.2-N LM285BX-1.2-N LM285BY-1.2-N		LM385B-1.2-N LM385BX-1.2-N LM385BY-1.2-N		LM385-1.2-N		Units (Limit)
			Tested Limit ⁽²⁾ (3)	Design Limit ⁽⁴⁾	Tested Limit ⁽²⁾	Design Limit ⁽⁴⁾	Tested Limit ⁽²⁾	Design Limit ⁽⁴⁾	
Reverse Breakdown Voltage	$T_A = 25^\circ\text{C}$, $10\mu\text{A} \leq I_R \leq 20\text{mA}$	1.23 5	1.223 1.247		1.223 1.247		1.205 1.260		V(Min) V(Max)
Minimum Operating Current		8	10	20	15	20	15	20	μA
	LM385M3-1.2-N						10	15	(Max)
Reverse Breakdown Voltage Change with Current	$10\mu\text{A} \leq I_R \leq 1\text{mA}$		1	1.5	1	1.5	1	1.5	mV (Max)
	$1\text{mA} \leq I_R \leq 20\text{mA}$		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	$I_R = 100\mu\text{A}$, $f = 20\text{Hz}$	1							Ω
Wideband Noise (rms)	$I_R = 100\mu\text{A}$, $10\text{Hz} \leq f \leq 10\text{kHz}$	60							μV
Long Term Stability	$I_R = 100\mu\text{A}$, $T = 1000\text{ Hr}$, $T_A = 25^\circ\text{C} \pm 0.1^\circ\text{C}$	20							ppm
Average Temperature Coefficient ⁽⁵⁾	$I_R = 100\mu\text{A}$								
	X Suffix		30		30				ppm/ $^\circ\text{C}$
	Y Suffix		50		50				ppm/ $^\circ\text{C}$
	All Others			150		150		150	ppm/ $^\circ\text{C}$ (Max)

(1) Parameters identified with boldface type apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^\circ\text{C}$.

(2) Production tested.

(3) A military RETS electrical specification is available on request.

(4) Specified by design. Not production tested. These limits are not used to calculate average outgoing quality levels.

(5) The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by $T_{\text{MAX}} - T_{\text{MIN}}$. The measured temperatures are -55°C , -40°C , 0°C , 25°C , 70°C , 85°C , 125°C .

THERMAL CHARACTERISTICS

Thermal Resistance	TO-92	TO	SOIC	SOT-23
θ_{JA} (junction to ambient)	180 $^\circ\text{C/W}$ (0.4" leads) 170 $^\circ\text{C/W}$ (0.125" leads)	440 $^\circ\text{C/W}$	165 $^\circ\text{C/W}$	283 $^\circ\text{C/W}$
θ_{JC} (junction to case)	N/A	80 $^\circ\text{C/W}$	N/A	N/A

TYPICAL PERFORMANCE CHARACTERISTICS

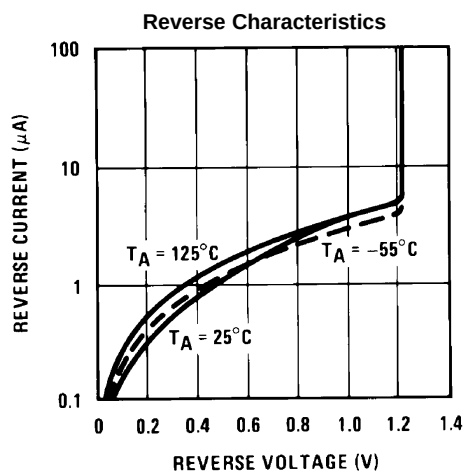


Figure 5.

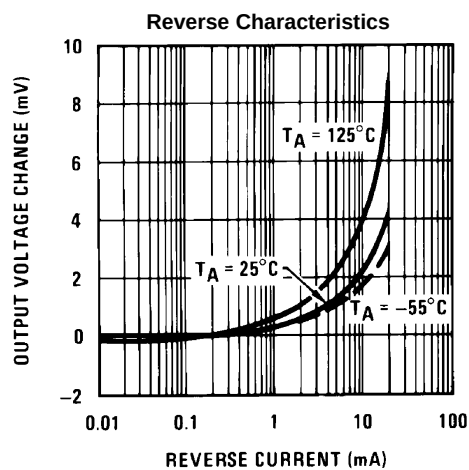


Figure 6.

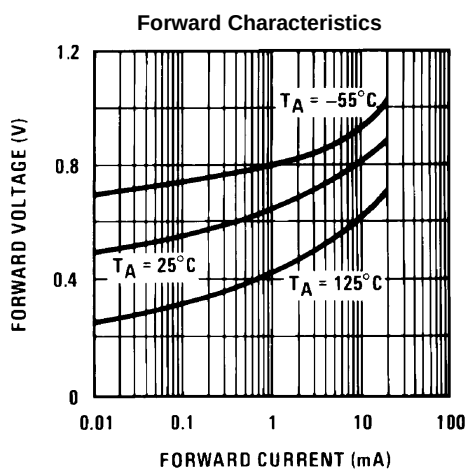


Figure 7.

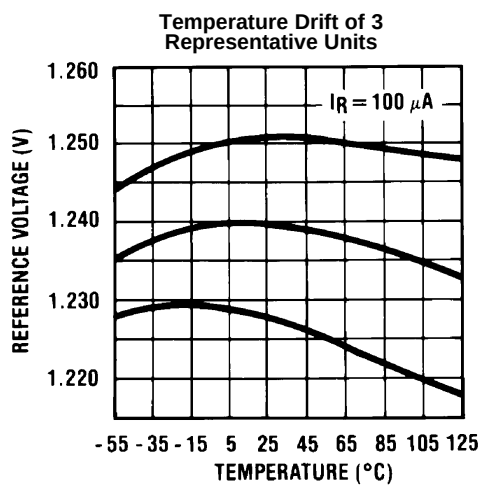


Figure 8.

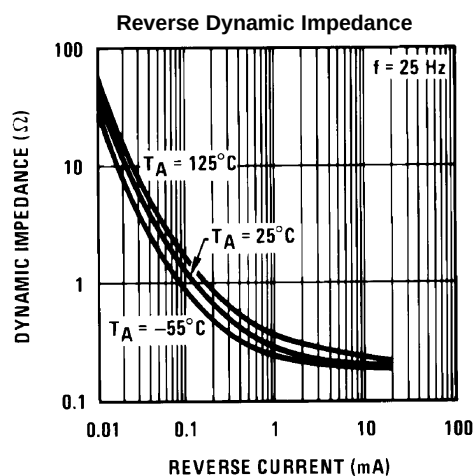


Figure 9.

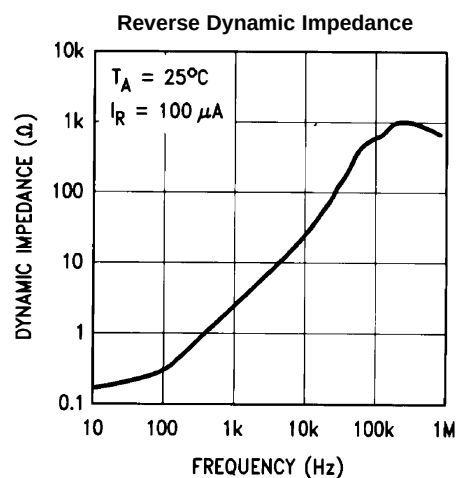


Figure 10.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

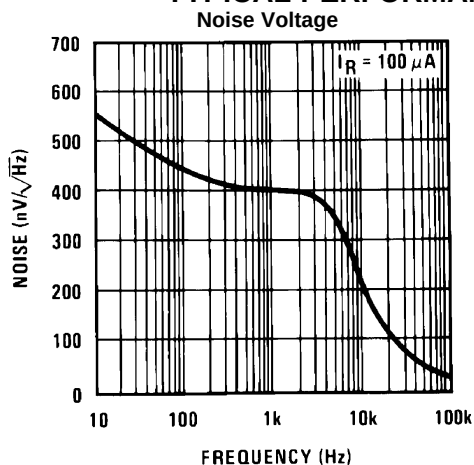


Figure 11.

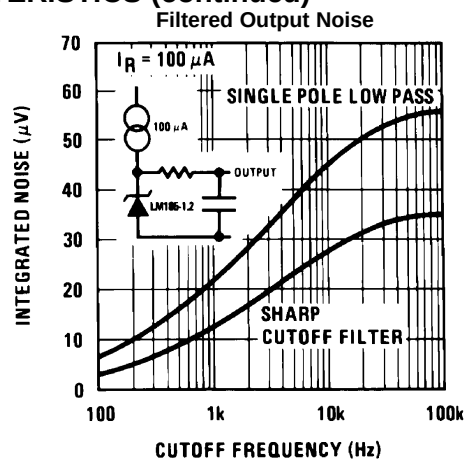


Figure 12.

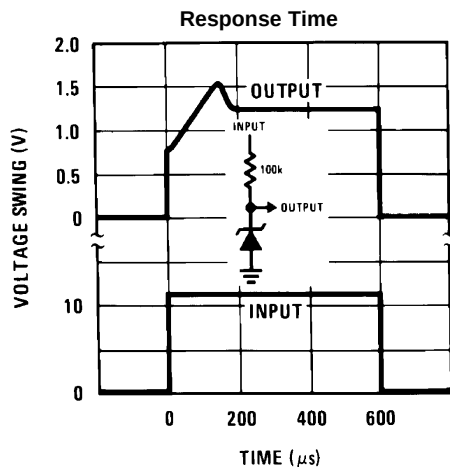


Figure 13.

TYPICAL APPLICATIONS

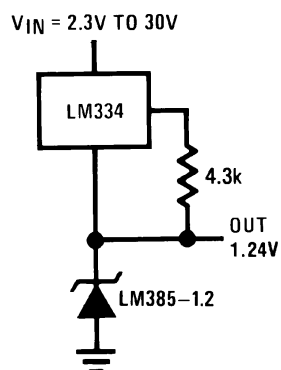


Figure 14. Wide Input Range Reference

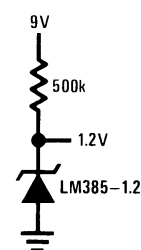


Figure 15. Micropower Reference from 9V Battery

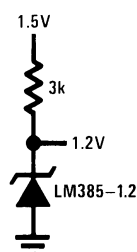


Figure 16. Reference from 1.5V Battery

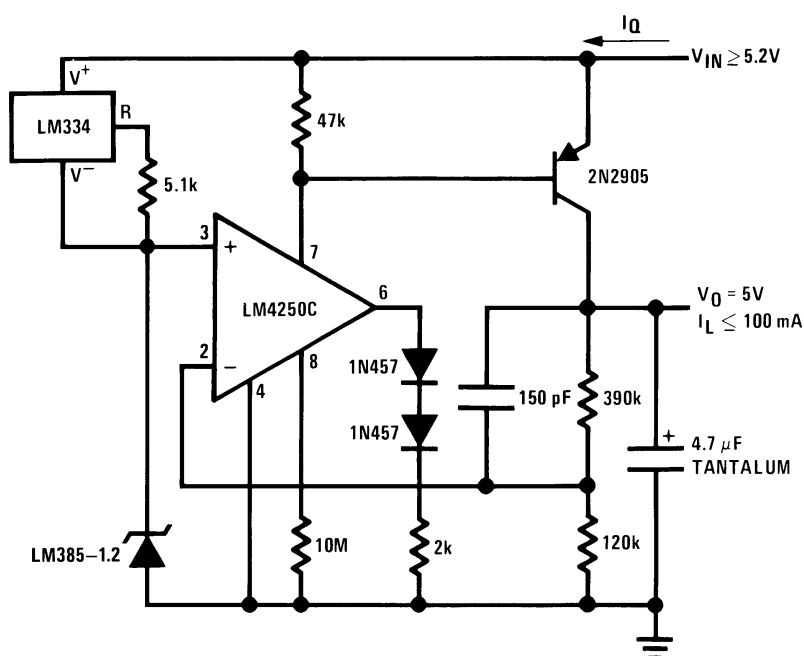
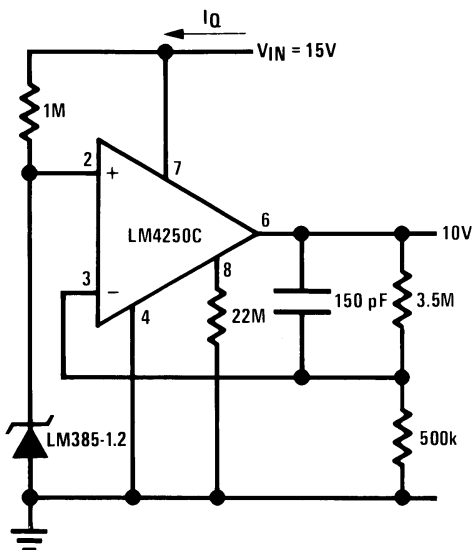
* $I_Q \approx 30\mu A$

Figure 17. Micropower* 5V Regulator



* $I_Q \approx 20\mu\text{A}$ standby current

Figure 18. Micropower* 10V Reference

$$*I_{OUT} = \frac{1.23\text{V}}{R2}$$

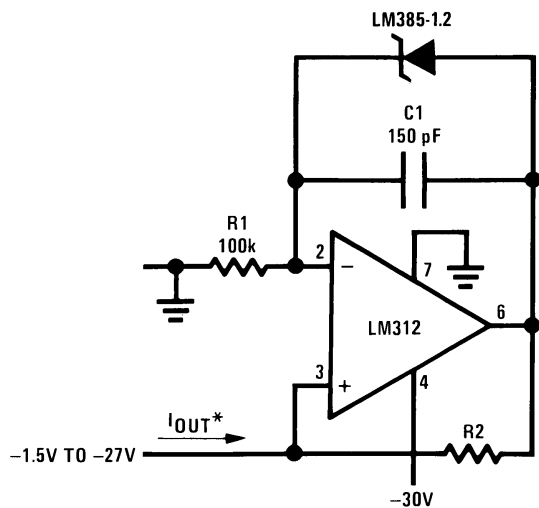


Figure 19.

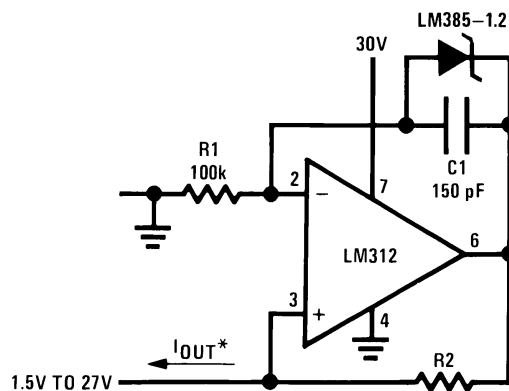
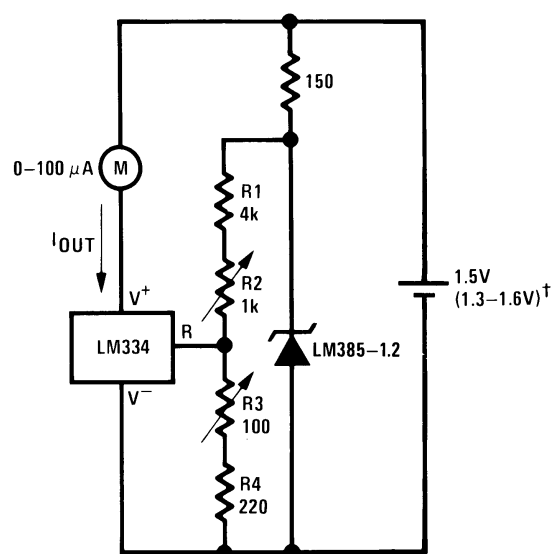
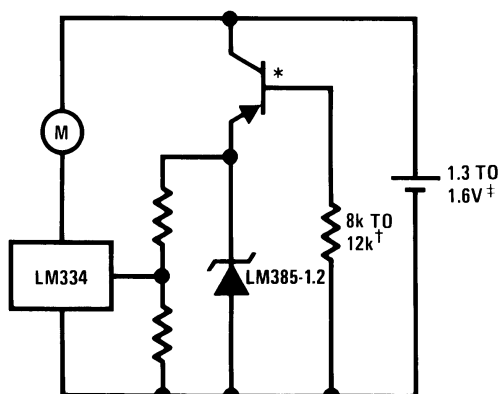


Figure 20. Precision 1μA to 1mA Current Sources

METER THERMOMETERS**Calibration**

1. Short LM385-1.2-N, adjust R3 for $I_{OUT} = \text{temp at } 1\mu\text{A}/^\circ\text{C}$
 2. Remove short, adjust R2 for correct reading in centigrade
- † I_Q at 1.3V=500 μA
 I_Q at 1.6V=2.4mA

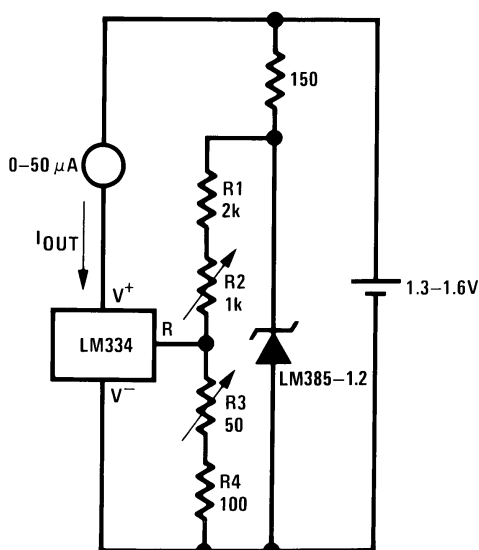
Figure 21. 0°C–100°C Thermometer**Figure 22.**

*2N3638 or 2N2907 select for inverse $H_{FE} \approx 5$

†Select for operation at 1.3V

‡ $I_Q \approx 600\mu\text{A}$ to $900\mu\text{A}$

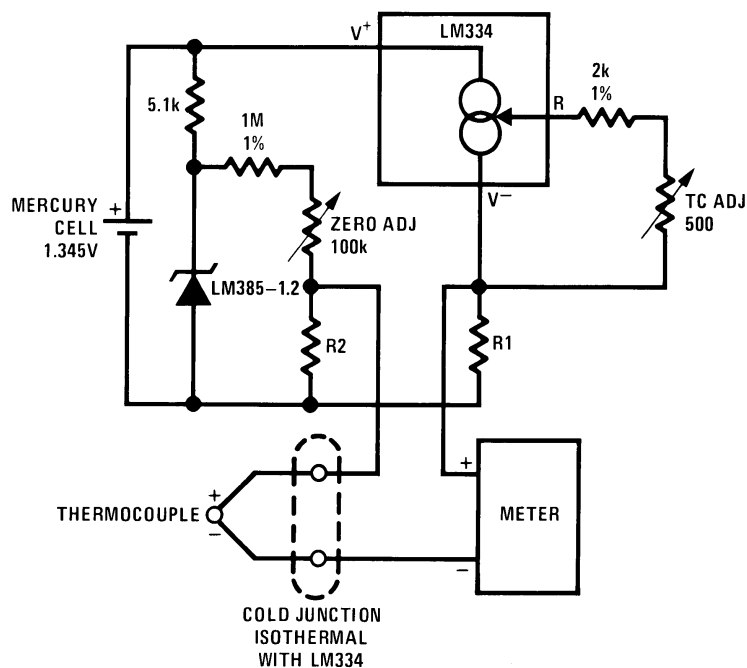
Figure 23. Lower Power Thermometer



Calibration

1. Short LM385-1.2-N, adjust R3 for $I_{OUT} = \text{temp}$ at $1.8\mu A/^{\circ}K$
2. Remove short, adjust R2 for correct reading in $^{\circ}F$

Figure 24. 0°F–50°F Thermometer



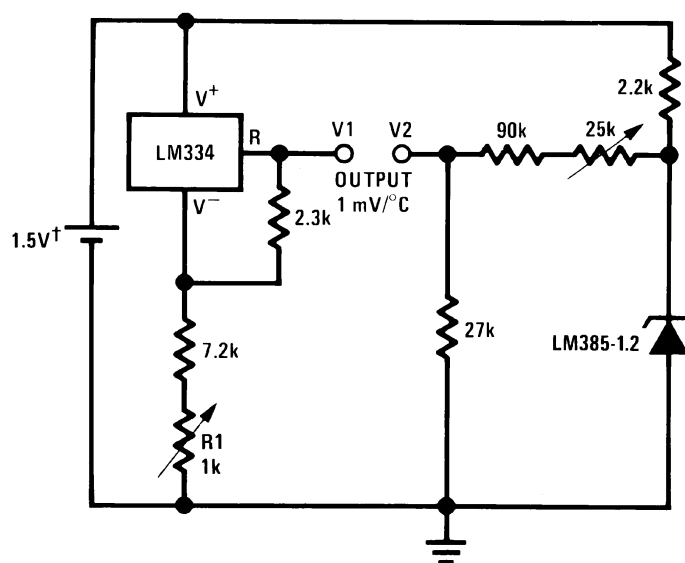
Adjustment Procedure

1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

Figure 25. Micropower Thermocouple Cold Junction Compensator

Thermocouple Type	Seebeck Coefficient ($\mu\text{V}/^\circ\text{C}$)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @ 25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
T	42.8	432	1k	12.77	11.78
K	40.8	412	953 Ω	12.17	11.17
S	6.4	63.4	150 Ω	1.908	1.766

Typical supply current 50 μA

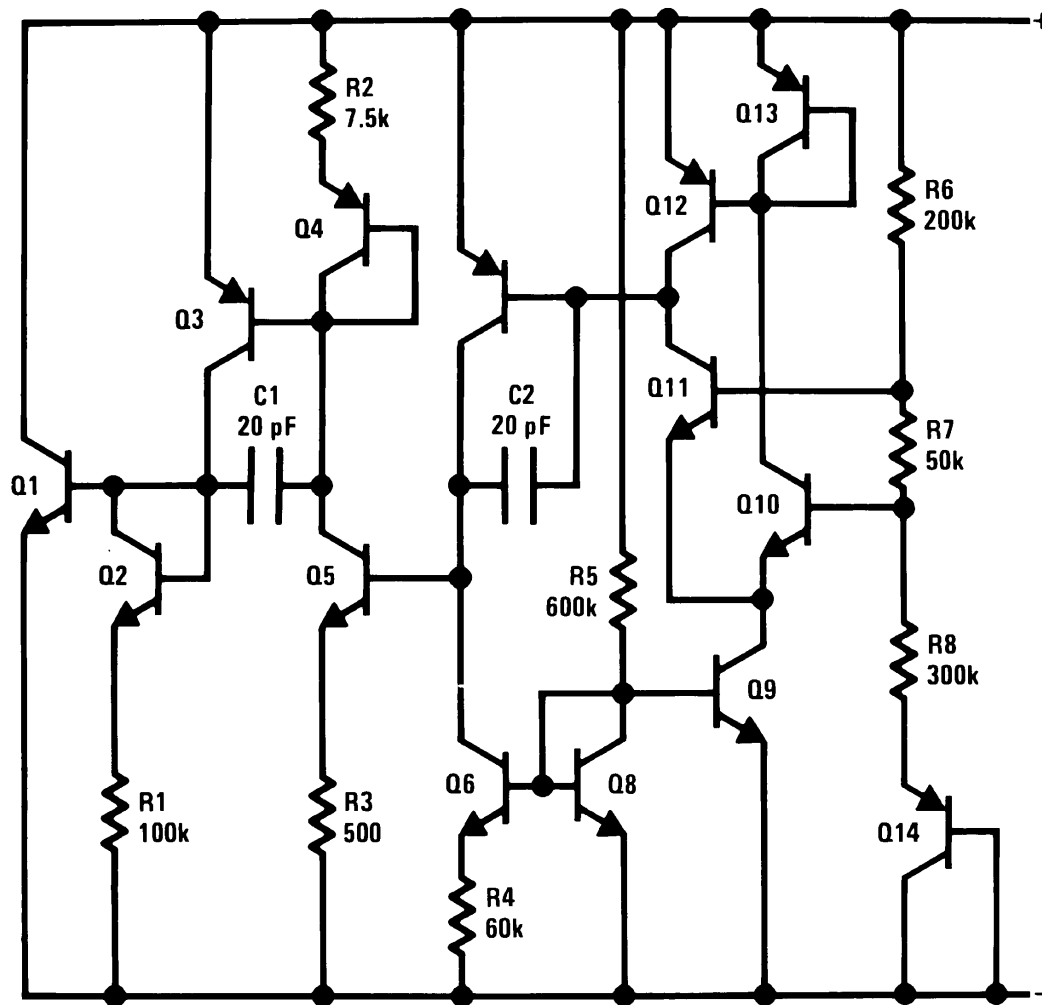


Calibration

1. Adjust R1 so that V1 = temp at 1mV/°K
 2. Adjust V2 to 273.2mV
- †I_Q for 1.3V to 1.6V battery voltage = 50 μA to 150 μA

Figure 26. Centigrade Thermometer

SCHEMATIC DIAGRAM



REVISION HISTORY

Changes from Revision D (April 2013) to Revision E	Page
• Changed layout of National Data Sheet to TI format	11

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM185BYH-1.2/NOPB	Active	Production	TO (NDU) 2	1000 BULK	Yes	SNAGCU	Level-1-NA-UNLIM	-55 to 125	(LM185BYH1.2, LM185BYH1.2)
LM185H-1.2/NOPB	Active	Production	TO (NDU) 2	1000 BULK	Yes	SNAGCU	Level-1-NA-UNLIM	-55 to 125	(LM185H1.2, LM185H1.2)
LM285BXM-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BX M1.2
LM285BXM-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BX M1.2
LM285BXM-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BX M1.2
LM285BXM-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BX M1.2
LM285BXZ-1.2/LFT4	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	Call TI	N/A for Pkg Type	-	285BX Z-1.2
LM285BXZ-1.2/LFT4.B	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	Call TI	N/A for Pkg Type	-40 to 85	285BX Z-1.2
LM285BXZ-1.2/NOPB	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	-40 to 85	285BX Z-1.2
LM285BXZ-1.2/NOPB.B	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	-40 to 85	285BX Z-1.2
LM285BYM-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BY M1.2
LM285BYM-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BY M1.2
LM285BYM-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BY M1.2
LM285BYM-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	285BY M1.2
LM285M-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM285 M1.2
LM285M-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM285 M1.2

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM285MX-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM285 M1.2
LM285MX-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	LM285 M1.2
LM285Z-1.2/NOPB	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	-40 to 85	LM28 5Z-1.2
LM285Z-1.2/NOPB.B	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	-40 to 85	LM28 5Z-1.2
LM385BM-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 BM1.2
LM385BM-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 BM1.2
LM385BMX-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 BM1.2
LM385BMX-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 BM1.2
LM385BXM-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BX M1.2
LM385BXM-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BX M1.2
LM385BXM-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BX M1.2
LM385BXM-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BX M1.2
LM385BXZ-1.2/NOPB	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	0 to 70	385BX Z-1.2
LM385BXZ-1.2/NOPB.B	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	0 to 70	385BX Z-1.2
LM385BYM-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BY M1.2
LM385BYM-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BY M1.2
LM385BYMX-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BY M1.2

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LM385BYMX-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	385BY M1.2
LM385BYZ-1.2/NOPB	Active	Production	TO-92 (LP) 3	1800 BULK	-	Call TI	N/A for Pkg Type	0 to 70	385BY Z-1.2
LM385BYZ-1.2/NOPB.B	Active	Production	TO-92 (LP) 3	1800 BULK	-	Call TI	N/A for Pkg Type	0 to 70	385BY Z-1.2
LM385BZ-1.2/NOPB	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	0 to 70	LM385 BZ1.2
LM385BZ-1.2/NOPB.B	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	0 to 70	LM385 BZ1.2
LM385M-1.2/NOPB	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 M1.2
LM385M-1.2/NOPB.B	Active	Production	SOIC (D) 8	95 TUBE	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 M1.2
LM385M3-1.2/NOPB	Active	Production	SOT-23 (DBZ) 3	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	R11
LM385M3-1.2/NOPB.B	Active	Production	SOT-23 (DBZ) 3	1000 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	R11
LM385M3X-1.2/NOPB	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	R11
LM385M3X-1.2/NOPB.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	R11
LM385MX-1.2/NOPB	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 M1.2
LM385MX-1.2/NOPB.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	LM385 M1.2
LM385Z-1.2/LFT3	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	-	LM385 Z-1.2
LM385Z-1.2/LFT3.B	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	0 to 70	LM385 Z-1.2
LM385Z-1.2/LFT4	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	-	LM385 Z-1.2
LM385Z-1.2/LFT4.B	Active	Production	TO-92 (LP) 3	2000 LARGE T&R	Yes	SN	N/A for Pkg Type	0 to 70	LM385 Z-1.2
LM385Z-1.2/NOPB	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	0 to 70	LM385 Z-1.2
LM385Z-1.2/NOPB.B	Active	Production	TO-92 (LP) 3	1800 BULK	Yes	Call TI	N/A for Pkg Type	0 to 70	LM385 Z-1.2

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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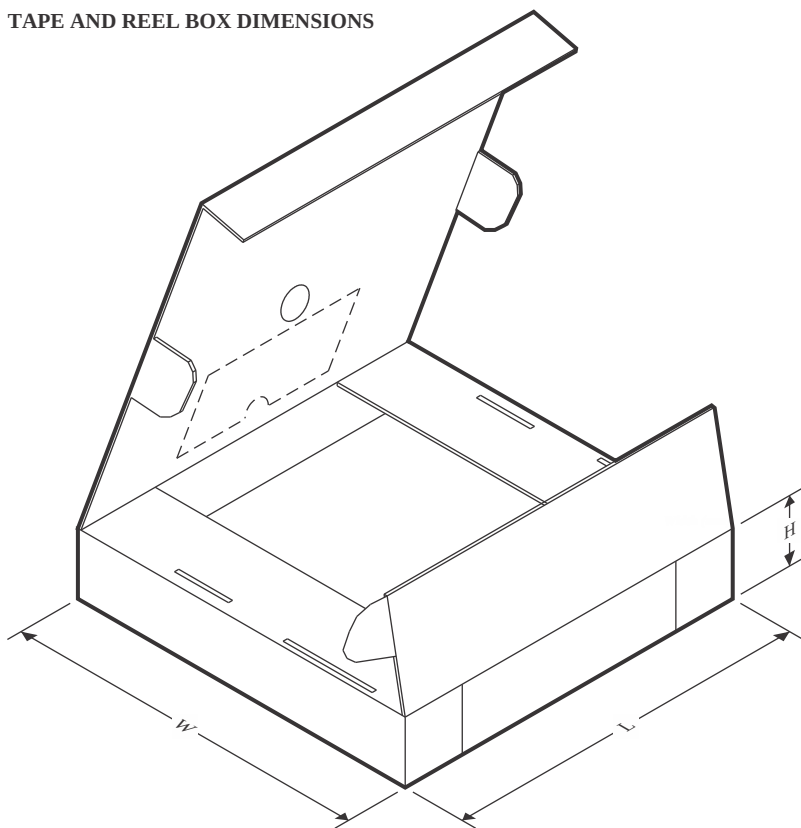
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM285BXM-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM285BYM-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM285MX-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BM-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BXM-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385BYM-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM385M3-1.2/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM385M3X-1.2/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM385MX-1.2/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

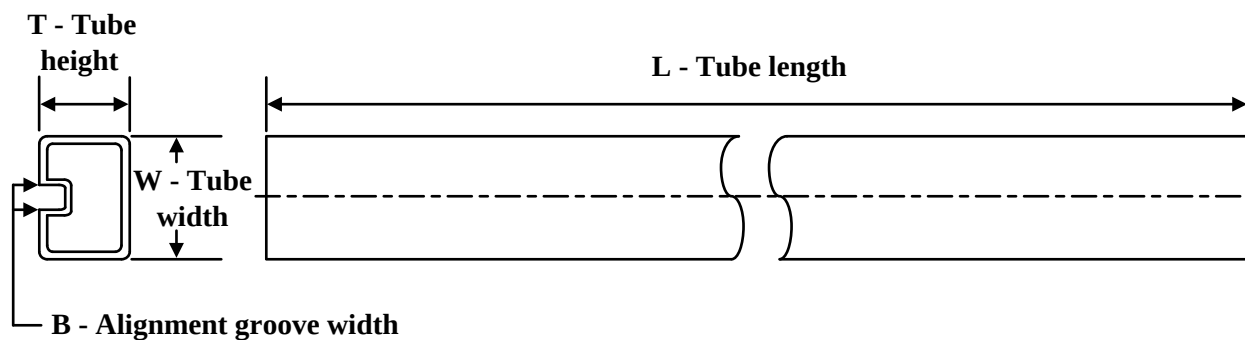
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

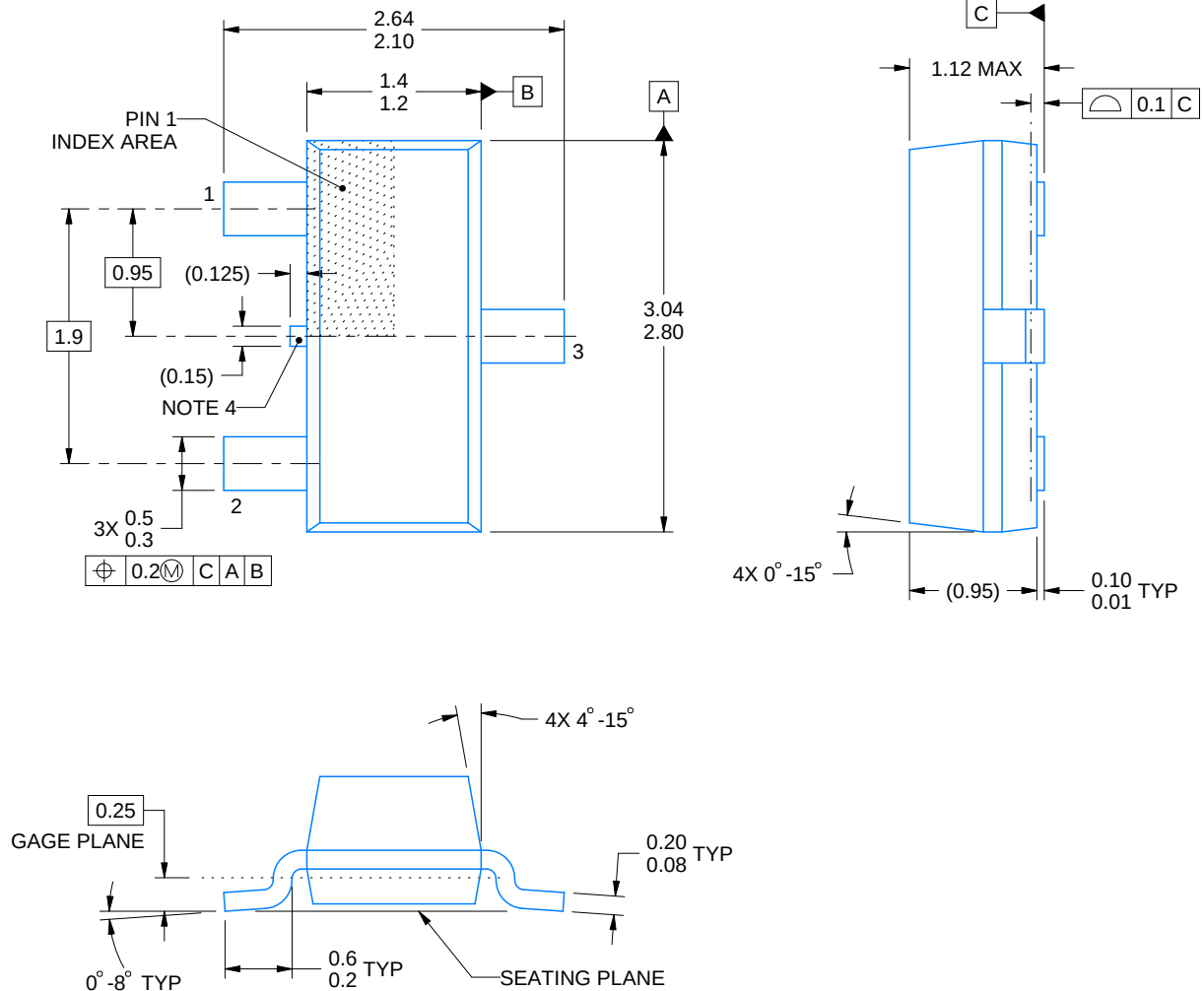
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM285BXM-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM285BYM-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM285MX-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BM-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BXM-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385BYM-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM385M3-1.2/NOPB	SOT-23	DBZ	3	1000	208.0	191.0	35.0
LM385M3X-1.2/NOPB	SOT-23	DBZ	3	3000	208.0	191.0	35.0
LM385MX-1.2/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LM285BXM-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM285BXM-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM285BYM-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM285BYM-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM285M-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM285M-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM385BM-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM385BM-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM385BXM-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM385BXM-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM385BYM-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM385BYM-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM385M-1.2/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM385M-1.2/NOPB.B	D	SOIC	8	95	495	8	4064	3.05



4214838/F 08/2024

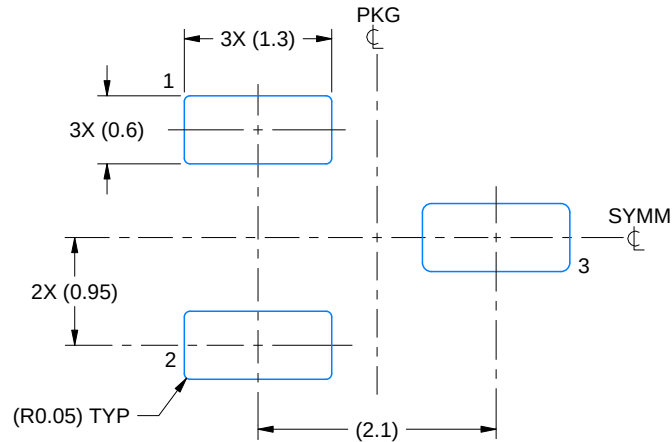
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

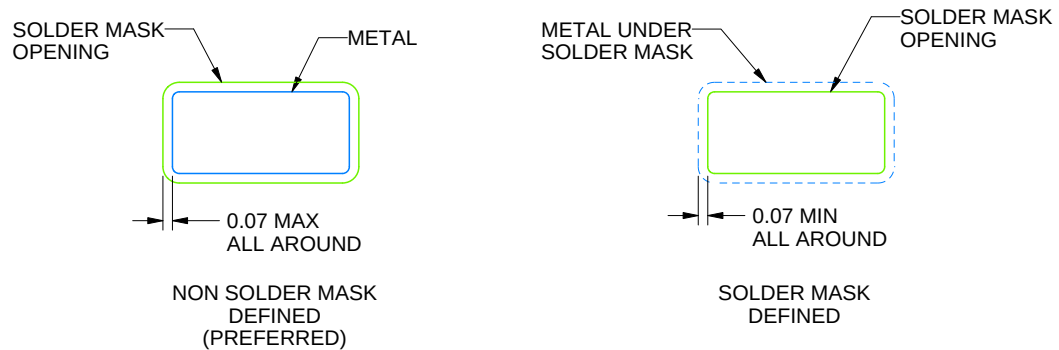
DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
SCALE:15X



SOLDER MASK DETAILS

4214838/F 08/2024

NOTES: (continued)

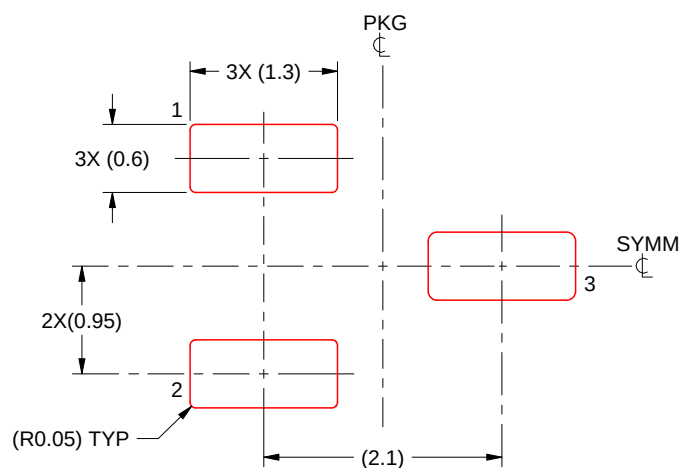
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR

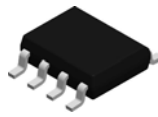


SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/F 08/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

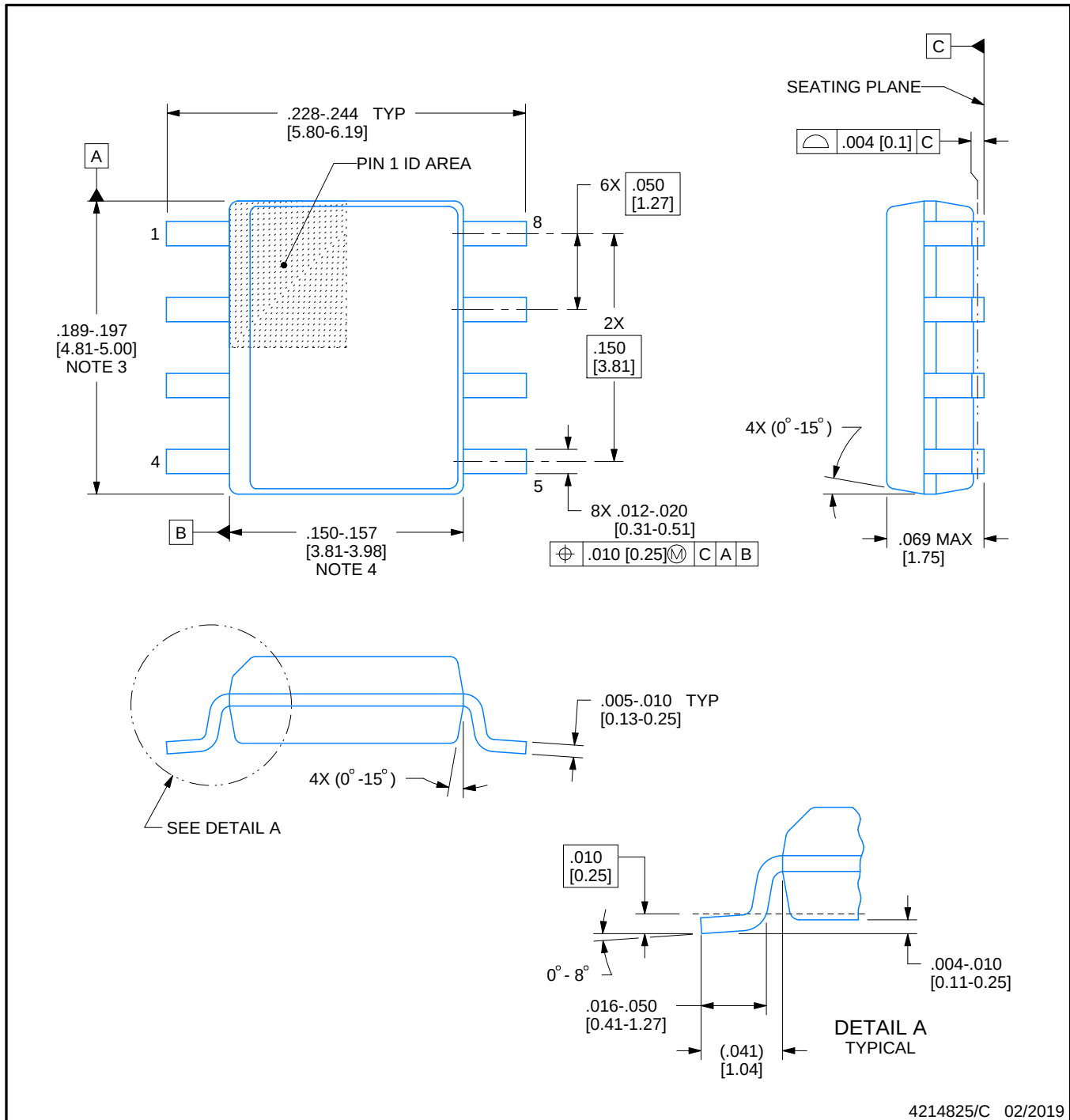


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

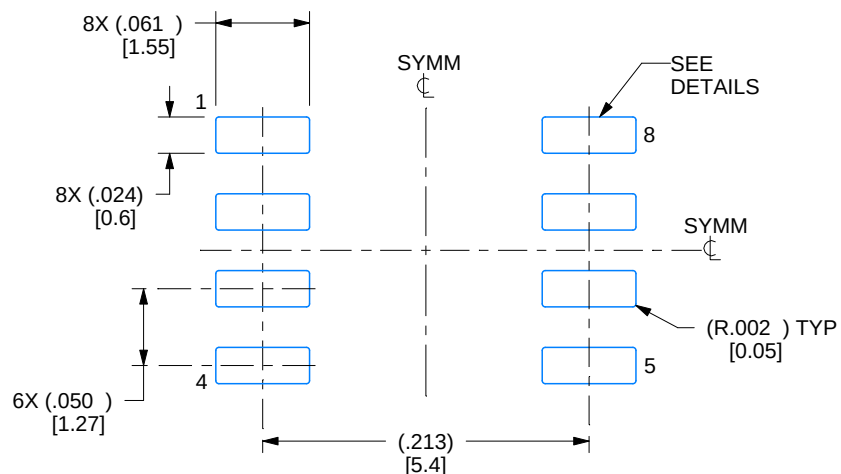
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

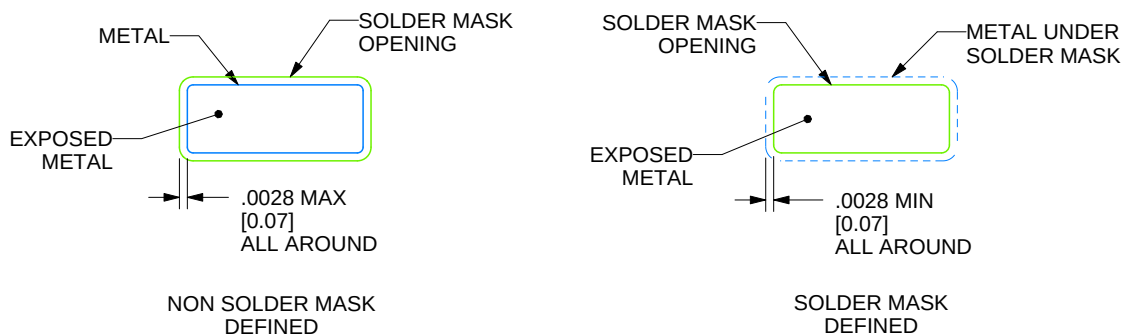
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

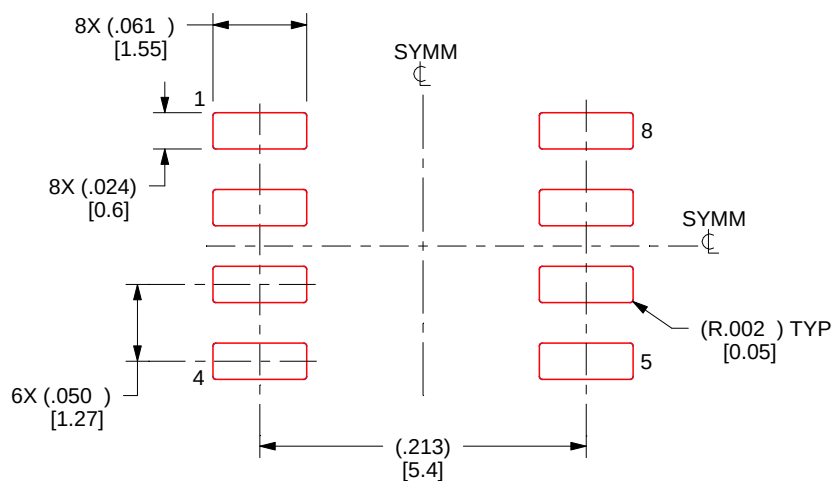
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

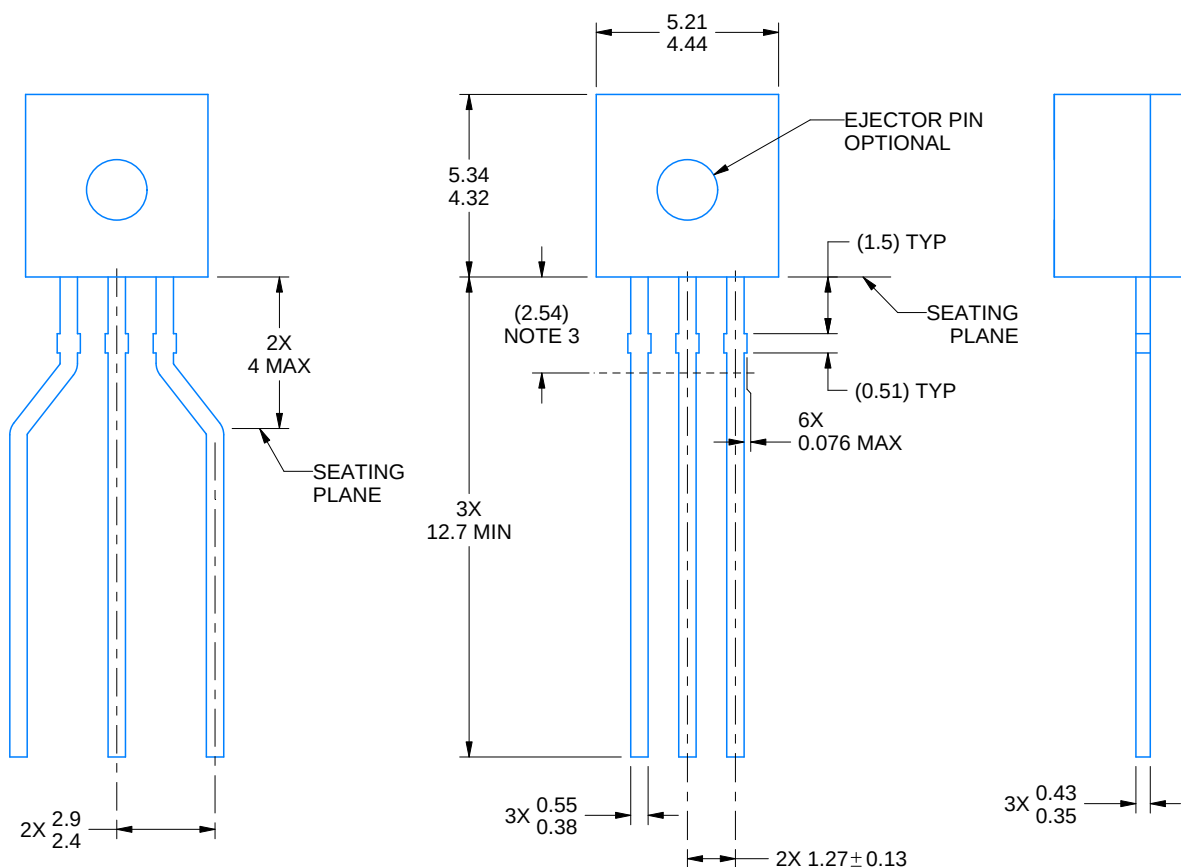
LP0003A



PACKAGE OUTLINE

TO-92 - 5.34 mm max height

TO-92



4215214/C 04/2025

NOTES:

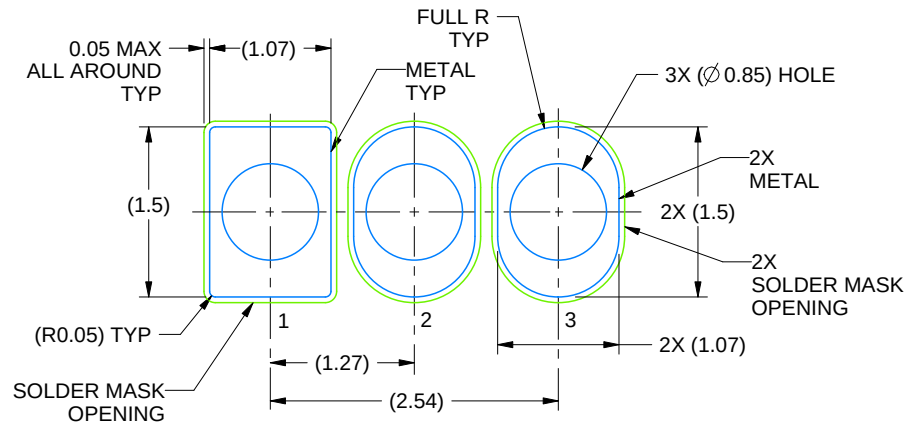
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Lead dimensions are not controlled within this area.
4. Reference JEDEC TO-226, variation AA.
5. Shipping method:
 - a. Straight lead option available in bulk pack only.
 - b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.

EXAMPLE BOARD LAYOUT

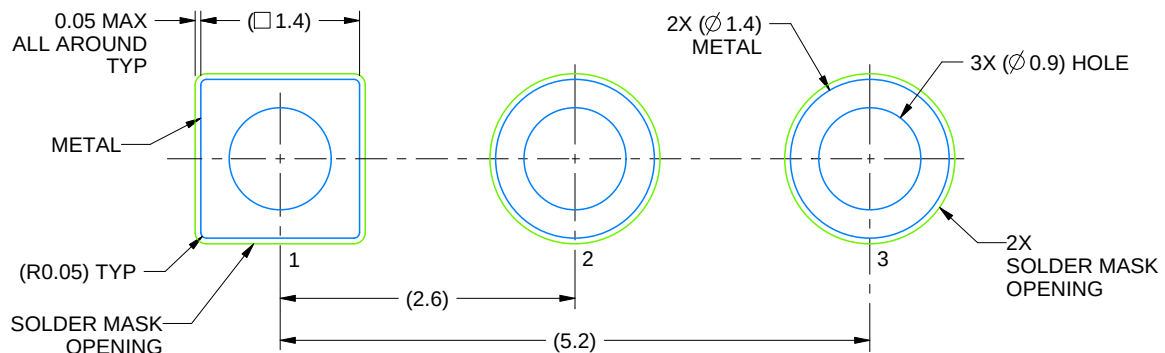
LP0003A

TO-92 - 5.34 mm max height

TO-92



LAND PATTERN EXAMPLE
STRAIGHT LEAD OPTION
NON-SOLDER MASK DEFINED
SCALE:15X



LAND PATTERN EXAMPLE
FORMED LEAD OPTION
NON-SOLDER MASK DEFINED
SCALE:15X

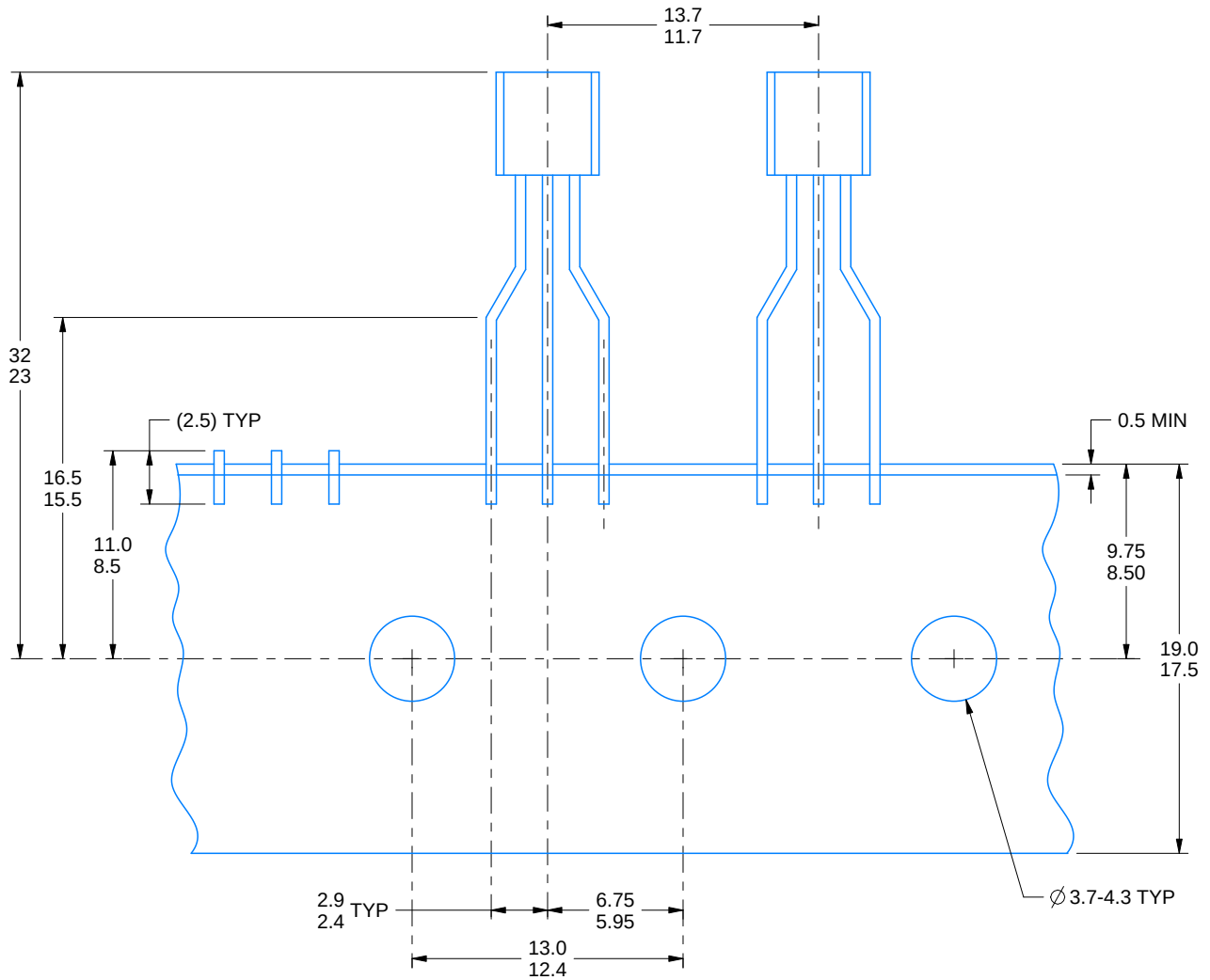
4215214/C 04/2025

TAPE SPECIFICATIONS

LP0003A

TO-92 - 5.34 mm max height

TO-92



FOR FORMED LEAD OPTION PACKAGE

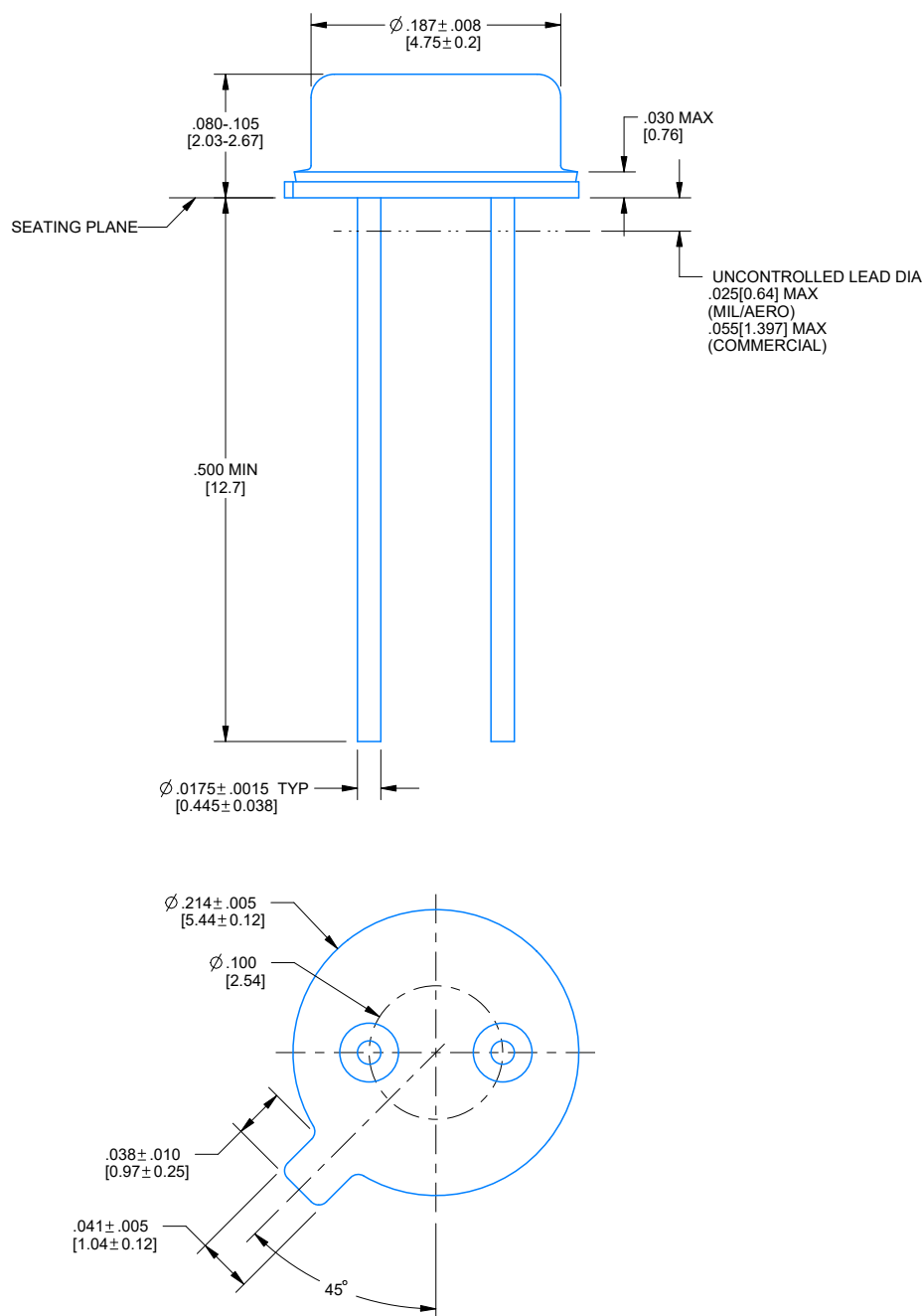
4215214/C 04/2025

PACKAGE OUTLINE

NDU0002A

TO-CAN - 2.67 mm max height

TRANSISTOR OUTLINE



4214762/B 09/2024

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

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